**FEATURES**

- **Input Voltage Range:** 8.5V to 100V
- **Programmable Volt-Second Clamp**
- **High Efficiency Control:** Active Clamp, Synchronous Rectification, Programmable Delays
- **Short-Circuit (Hiccup Mode) Overcurrent Protection**
- **Programmable Soft-Start/Stop**
- **Programmable OVLO and UVLO with Hysteresis**
- **Programmable Frequency (100kHz to 500kHz)**
- **Synchronizable to an External Clock**

**APPLICATIONS**

- Industrial, Automotive and Military Systems
- 48V Telecommunication Isolated Power Supplies

**DESCRIPTION**

The **LT®3753** is a current mode PWM controller optimized for an active clamp forward converter topology, allowing up to 100V input operation.

A programmable volt-second clamp allows primary switch duty cycles above 50% for high switch, transformer and rectifier utilization. Active clamp control reduces switch voltage stress and increases efficiency. A synchronous output is available for controlling secondary side synchronous rectification.

The LT3753 is available in a 38-lead plastic TSSOP package with missing pins for high voltage spacings.

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**TYPICAL APPLICATION**

36V to 72V, 5V/20A Active Clamp Isolated Forward Converter
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For more information www.analog.com
**ABSOLUTE MAXIMUM RATINGS**

*(Note 1)*

- $V_{\text{IN}}$ ................................................................. 100V
- $V_{\text{UVLO, UVSEC, OVLO}}$ .......................................... 20V
- $V_{\text{INTVCC, SS2}}$ .................................................. 16V
- $V_{\text{FB, SYNC}}$ ......................................................... 6V
- $V_{\text{SS1, COMP, TEST1, RT}}$ ....................................... 3V
- $I_{\text{SENSEP, ISENSEN, OC, TEST2}}$ .............................. 0.35V
- $I_{\text{IVSEC}}$ .................................................................. $–250\mu$A

Operating Junction Temperature Range (Notes 2, 3)

- LT3753EFE ........................................... $–40°C$ to $125°C$
- LT3753IFE ........................................... $–40°C$ to $125°C$
- LT3753HFE ........................................... $–40°C$ to $150°C$
- LT3753MPFE .......................................... $–55°C$ to $150°C$

Storage Temperature Range .................. $–65°C$ to $150°C$

Lead Temperature (Soldering, 10 Sec) .......... $300°C$

**ORDER INFORMATION**

<table>
<thead>
<tr>
<th>LEAD FREE FINISH</th>
<th>TAPE AND REEL</th>
<th>PART MARKING*</th>
<th>PACKAGE DESCRIPTION</th>
<th>TEMPERATURE RANGE</th>
</tr>
</thead>
<tbody>
<tr>
<td>LT3753EFE#PBF</td>
<td>LT3753EFE#TRPBF</td>
<td>LT3753FE</td>
<td>38-Lead Plastic TSSOP</td>
<td>$–40°C$ to $125°C$</td>
</tr>
<tr>
<td>LT3753IFE#PBF</td>
<td>LT3753IFE#TRPBF</td>
<td>LT3753FE</td>
<td>38-Lead Plastic TSSOP</td>
<td>$–40°C$ to $125°C$</td>
</tr>
<tr>
<td>LT3753HFE#PBF</td>
<td>LT3753HFE#TRPBF</td>
<td>LT3753FE</td>
<td>38-Lead Plastic TSSOP</td>
<td>$–40°C$ to $150°C$</td>
</tr>
<tr>
<td>LT3753MPFE#PBF</td>
<td>LT3753MPFE#TRPBF</td>
<td>LT3753FE</td>
<td>38-Lead Plastic TSSOP</td>
<td>$–55°C$ to $150°C$</td>
</tr>
</tbody>
</table>

Contact the factory for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

**Tape and reel specifications.** Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.
## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ C$. $V_{IN} = 12V$, $UVLO_{VSEC} = 2.5V$.

### PARAMETER CONDITIONS

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>Operational Input Voltage</td>
<td>●</td>
<td>8.5</td>
<td>100</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN(ON)}$</td>
<td>●</td>
<td>7.75</td>
<td>8.4</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN(OFF)}$</td>
<td>●</td>
<td>7.42</td>
<td></td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN(ON/OFF)}$ Hysteresis</td>
<td>●</td>
<td>0.11</td>
<td>0.55</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN}$ Quiescent Current</td>
<td>FB = 1.5V (Not Switching)</td>
<td>5.9</td>
<td>7.5</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>$UVLO_{VSEC}$ Micropower Threshold ($V_{SD}$)</td>
<td>$V_{IN} &lt; 20\mu A$</td>
<td>0.2</td>
<td>0.6</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN}$ Shutdown Current (Micropower)</td>
<td>$UVLO_{VSEC} = 0.2V$</td>
<td>20</td>
<td>40</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>$UVLO_{VSEC}$ Threshold ($V_{SYS_{UV}}$)</td>
<td>●</td>
<td>1.180</td>
<td>1.320</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN}$ Shutdown Current (After Soft-Stop)</td>
<td>$UVLO_{VSEC} = 1V$</td>
<td>165</td>
<td>220</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>$UVLO_{VSEC}$ (ON) Current</td>
<td>$UVLO_{VSEC} = V_{SYS_{UV}} + 50mV$</td>
<td>0</td>
<td></td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>$UVLO_{VSEC}$ (OFF) Current</td>
<td>$UVLO_{VSEC} = V_{SYS_{UV}} - 50mV$</td>
<td>4</td>
<td>6.0</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>Hysteresis Current</td>
<td>(Note 13)</td>
<td>5</td>
<td>25</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>OVLO (Rising) (No Switching, Reset SS1)</td>
<td>●</td>
<td>1.220</td>
<td>1.280</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>OVLO (Falling) (Restart SS1)</td>
<td>●</td>
<td>1.215</td>
<td></td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>OVLO Hysteresis</td>
<td>●</td>
<td>23</td>
<td>47</td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>OVLO Pin Current (Note 8)</td>
<td>$OVLO = 0V$</td>
<td>5</td>
<td>100</td>
<td>nA</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$OVLO = 1.5V (SS1 = 2.7V)$</td>
<td>0.9</td>
<td></td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$OVLO = 1.5V (SS1 = 1.0V)$</td>
<td>5</td>
<td>100</td>
<td>nA</td>
<td></td>
</tr>
</tbody>
</table>

### Oscillator

<table>
<thead>
<tr>
<th>FREQUENCY</th>
<th>$f_{OSC} = 100kHz$</th>
<th>$f_{OSC} = 300kHz$</th>
<th>$f_{OSC} = 500kHz$</th>
<th>$f_{OSC}$ Line Regulation</th>
<th>Frequency and $D_{VSEC}$ Foldback Ratio (Fold)</th>
<th>SYNC Input High Threshold</th>
<th>SYNC Input Low Threshold</th>
<th>SYNC Pin Current</th>
<th>SYNC Frequency/Programmed $f_{OSC}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_T$</td>
<td>$R_T = 82.5k$</td>
<td>$R_T = 24.9k$</td>
<td>$R_T = 14k$</td>
<td>$R_T = 24.9k, 8.5V &lt; V_{IN} &lt; 100V$</td>
<td>$SS1 = V_{SSACT} + 25mV, SS2 = 2.7V$</td>
<td>● 1.2 1.8</td>
<td>● 0.6 1.025</td>
<td>● 75</td>
<td>1.0 1.25 kHz/kHz</td>
</tr>
</tbody>
</table>

### Linear Regulator ($INTV_{CC}$)

<table>
<thead>
<tr>
<th>INTV_{CC} Regulation Voltage</th>
<th>$INTV_{CC} = 0V$</th>
<th>$INTV_{CC} = 8.75V, I_{INTVCC} = 10mA$</th>
<th>$INTV_{CC}$ UVLO(+) (Start Switching)</th>
<th>$INTV_{CC}$ UVLO(+) (Stop Switching)</th>
<th>$INTV_{CC}$ UVLO Hysteresis (Stop Switching)</th>
<th>$INTV_{CC}$ OVLO(+) (Start Switching)</th>
<th>$INTV_{CC}$ OVLO(+) (Stop Switching)</th>
<th>$INTV_{CC}$ OVLO Hysteresis (Stop Switching)</th>
<th>$INTV_{CC}$ Current Limit</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>● 9.4 10 10.4</td>
<td>9.6 7.4 7.3</td>
<td>0.1 0.2 0.3</td>
<td>15.4 16 16.7</td>
<td>0.38 0.5 0.67</td>
<td>9.5 13 17</td>
<td>19 27 32</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ C$, $V_{IN} = 12V$, $UVLO_{\text{VSEC}} = 2.5V$.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>Error Amplifier</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>FB Reference Voltage</td>
<td></td>
<td>●</td>
<td>1.220</td>
<td>1.250</td>
<td>1.275</td>
</tr>
<tr>
<td>FB Line Reg</td>
<td>$8.5V &lt; V_{IN} &lt; 100V$</td>
<td>0.1</td>
<td>0.3</td>
<td></td>
<td>mV/V</td>
</tr>
<tr>
<td>FB Input Load Reg</td>
<td>$\text{COMP_SW - 0.1V &lt; COMP &lt; COMP_VOH - 0.1V}$</td>
<td>0.1</td>
<td>0.3</td>
<td></td>
<td>mV/V</td>
</tr>
<tr>
<td>Open-Loop Voltage Gain</td>
<td></td>
<td>85</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Unity-Gain Bandwidth</td>
<td></td>
<td>2.5</td>
<td></td>
<td></td>
<td>MHz</td>
</tr>
<tr>
<td>COMP Source Current</td>
<td>$\text{FB = 1V, COMP = 1.75V (Note 8)}$</td>
<td>6</td>
<td>11</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>COMP Sink Current</td>
<td>$\text{FB = 1.5V, COMP = 1.75V}$</td>
<td>6.5</td>
<td>11.5</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>COMP Output High Clamp</td>
<td></td>
<td>2.6</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Current Sense</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$I_{\text{SENSE}}$ Maximum Threshold</td>
<td>$\text{FB = 1V, OC = 0V}$</td>
<td>180</td>
<td>220</td>
<td>260</td>
<td>mV</td>
</tr>
<tr>
<td>COMP Current Mode Gain</td>
<td>$\Delta V_{\text{COMP}}/\Delta I_{\text{SENSE}}$</td>
<td>6.1</td>
<td></td>
<td></td>
<td>V/V</td>
</tr>
<tr>
<td>$I_{\text{SENSE}}$ Input Current (D = 0%)</td>
<td></td>
<td>2</td>
<td></td>
<td></td>
<td>μA</td>
</tr>
<tr>
<td>$I_{\text{SENSE}}$ Input Current (D = 80%)</td>
<td></td>
<td>33</td>
<td></td>
<td></td>
<td>μA</td>
</tr>
<tr>
<td>$I_{\text{SENSE}}$ Input Current (D = 100%)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>μA</td>
</tr>
<tr>
<td>OC Overcurrent Threshold</td>
<td></td>
<td>●</td>
<td>82.5</td>
<td>96</td>
<td>107.5</td>
</tr>
<tr>
<td>AOUT Driver (Active Clamp Switch Control)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>AOUT Rise Time</td>
<td></td>
<td>23</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>AOUT Fall Time</td>
<td></td>
<td>19</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>AOUT Low Level</td>
<td></td>
<td>0.1</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>AOUT High Level</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>AOUT High Level in Shutdown</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>SOUT Driver (Synchronous Rectification Control)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>SOUT Rise Time</td>
<td></td>
<td>21</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>SOUT Fall Time</td>
<td></td>
<td>19</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>SOUT Low Level</td>
<td></td>
<td>0.1</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>SOUT High Level</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>SOUT High Level in Shutdown</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>OUT (Fall) to AOUT Edge (tOA)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>SOUT (Fall) to OUT (Rise) (tSO = tAO – tAS)</td>
<td>$\text{CSOUT = CSOUT = 1nF, COUT = 1nF, INTVCC = 12V}$</td>
<td>70</td>
<td>110</td>
<td>132</td>
<td>ns</td>
</tr>
<tr>
<td>OUT (Fall) to AOUT Edge (tOA)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>AOUT Edge to OUT (Rise): (tAO)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>AOUT Edge to OUT (Fall): (tAS)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>OUT (Fall) to AOUT Edge (tOA)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>ns</td>
</tr>
</tbody>
</table>

For more information [www.analog.com](http://www.analog.com)
### ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at TA = 25°C. VIN = 12V, UVLO_VSEC = 2.5V.

#### OUT (Fall) to SOUT (Rise): (tOS)

<table>
<thead>
<tr>
<th>PARAMETER CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>C_SOUT = 1nF, C_OUT = 3.3nF, INTVCC = 12V R_TOS = 14.7k</td>
<td>52</td>
<td>68</td>
<td>84</td>
<td>ns</td>
</tr>
<tr>
<td>R_TOS = 44.2k (Note 12)</td>
<td>102</td>
<td>133</td>
<td>164</td>
<td>ns</td>
</tr>
</tbody>
</table>

#### OUT Driver (Main Power Switch Control)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>OUT Rise Time</td>
<td>C_OUT = 3.3nF, INTVCC = 12V (Note 5)</td>
<td>19</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>OUT Fall Time</td>
<td>C_OUT = 3.3nF, INTVCC = 12V (Note 5)</td>
<td>20</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>OUT Low Level</td>
<td></td>
<td>0.1</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>OUT High Level</td>
<td>INTVCC = 12V</td>
<td>11.9</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>OUT Low Level in Shutdown</td>
<td>UVLO_VSEC = 0V, INTVCC = 8V, IOUT = 1mA Into the Pin</td>
<td>0.25</td>
<td></td>
<td></td>
<td>V</td>
</tr>
</tbody>
</table>

#### OUT (Volt-Sec) Max Duty Cycle Clamp

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>D_VSEC (1 • System Input (Min)) × 100</td>
<td>RT = 22.6k, R_INVSEC = 51.1k, FB = 1V, SS1 = 2.7V UVLO_VSEC = 1.25V UVLO_VSEC = 2.50V UVLO_VSEC = 5.00V</td>
<td>68.5</td>
<td>72.5</td>
<td>76.2</td>
<td>%</td>
</tr>
<tr>
<td>D_VSEC (2 • System Input (Min)) × 100</td>
<td></td>
<td>34.3</td>
<td>36.5</td>
<td>38.7</td>
<td>%</td>
</tr>
<tr>
<td>D_VSEC (4 • System Input (Min)) × 100</td>
<td></td>
<td>17.5</td>
<td>18.6</td>
<td>19.7</td>
<td>%</td>
</tr>
</tbody>
</table>

#### OUT Minimum ON Time

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>C_OUT = 3.3nF, INTVCC = 12V (Note 7)</td>
<td>RTBLNK = 14.7k</td>
<td>325</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>RTBLNK = 73.2k (Note 14)</td>
<td>454</td>
<td></td>
<td></td>
<td>ns</td>
<td></td>
</tr>
</tbody>
</table>

#### SS1 Pin (Soft-Start: Frequency and D_VSEC) (Soft-Stop: COMP Pin, Frequency and D_VSEC)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>SS1 Reset Threshold (V_SS1(RTH))</td>
<td></td>
<td>150</td>
<td></td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>SS1 Active Threshold (V_SS1(ACT))</td>
<td>(Allow Switching)</td>
<td>1.25</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>SS1 Charge Current (Soft-Start)</td>
<td>SS1 = 1.5V (Note 8)</td>
<td>7</td>
<td>11.5</td>
<td>16</td>
<td>μA</td>
</tr>
<tr>
<td>SS1 Discharge Current (Soft-Stop)</td>
<td>SS1 = 1V, UVLO_VSEC = VSYS_UV – 50mV</td>
<td>6.4</td>
<td>10.5</td>
<td>14.6</td>
<td>μA</td>
</tr>
<tr>
<td>SS1 Discharge Current (Hard Stop)</td>
<td>OC &gt; OC Threshold</td>
<td>0.9</td>
<td></td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>INTVCC &lt; INTVCC UVLO(−)</td>
<td>SS1 = 1V</td>
<td>0.9</td>
<td></td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>OVLO &gt; OVLO(+)</td>
<td>SS1 = 1V</td>
<td>0.9</td>
<td></td>
<td></td>
<td>mA</td>
</tr>
</tbody>
</table>

#### SS2 Pin (Soft-Start: Comp Pin)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>SS2 Discharge Current</td>
<td>SS1 &lt; V_SS(ACT), SS2 = 2.5V</td>
<td>2.8</td>
<td></td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>SS2 Charge Current</td>
<td>SS1 &gt; V_SS(ACT), SS2 = 1.5V</td>
<td>11</td>
<td>21</td>
<td>28</td>
<td>μA</td>
</tr>
</tbody>
</table>

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** The LT3753EFE is guaranteed to meet performance specifications from 0°C to 125°C junction temperature. Specifications over the –40°C to 125°C operating junction temperature range are assured by design, characterization and correlation with statistical process controls. The LT3753IFE is guaranteed to meet performance specifications from –40°C to 125°C junction temperature. The LT3753HFE is guaranteed to meet performance specifications from –40°C to 150°C junction temperature. The LT3753MPFE is tested and guaranteed to meet performance specifications from –55°C to 150°C junction temperature.

**Note 3:** For maximum operating ambient temperature, see the Thermal Calculations section in the Applications Information section.

**Note 4:** SYNC minimum and maximum thresholds are guaranteed by SYNC frequency range test using a clock input with guard banded SYNC levels of 0.7V low level and 1.7V high level.

**Note 5:** Rise and fall times are measured between 10% and 90% of gate driver supply voltage.

**Note 6:** Guaranteed by design.

**Note 7:** ON times are measured between rising and falling edges at 50% of gate driver supply voltage.

**Note 8:** Current flows out of pin.

**Note 9:** Guaranteed by correlation to RTAS = 73.2k test.

**Note 10:** tOA timing guaranteed by design based on correlation to measured tAO timing.

**Note 11:** Guaranteed by correlation to RTAO = 44.2k test.

**Note 12:** Guaranteed by correlation to R_TOS = 14.7k test.

**Note 13:** A 2µs one-shot of 20µA from the UVLO_VSEC pin allows communication between ICs to begin shutdown (useful when stacking supplies for more power (= inputs in parallel/outputs in series)). The current is tested in a static test mode. The 2µs one-shot is guaranteed by design.

**Note 14:** Guaranteed by correlation to RTBLNK = 14.7k test.
TYPICAL PERFORMANCE CHARACTERISTICS  \( T_A = 25^\circ\text{C} \), unless otherwise noted.

- **VIN** Shutdown Current vs Junction Temperature
- **VIN(ON), VIN(OFF)** Thresholds vs Junction Temperature
- **VIN Quiescent Current** vs Junction Temperature
- **UVLO_VSEC Turn-On Threshold** vs Junction Temperature
- **UVLO_VSEC Hysteresis Current** vs Junction Temperature
- **INTVCC in Dropout at **VIN** = 8.75V** vs Current, Junction Temperature
- **INTVCC UVLO Thresholds** vs Junction Temperature
- **INTVCC Regulation Voltage** vs Current, Junction Temperature
- **SS1 Soft-Start/Soft-Stop Pin Currents** vs Junction Temperature

For more information [www.analog.com](http://www.analog.com)
TYPICAL PERFORMANCE CHARACTERISTICS  \( T_A = 25^\circ\text{C} \), unless otherwise noted.

### SS1 High, Active and Reset Levels vs Junction Temperature

- SS1 HIGH LEVEL
- SS1 ACTIVE LEVEL (ALLOW FORWARD CONVERTER SWITCHING)
- SS1 RESET LEVEL (RESET SS1 LATCH)

### SS2 Soft-Start Charge Current vs Junction Temperature

- SS2 SOFT-START CHARGE CURRENT

### Switching Frequency vs SS1 Pin Voltage

### Switching Frequency vs Junction Temperature

### FB Reference Voltage vs Junction Temperature

### ISENSEP Maximum Threshold – VSLP vs Duty Cycle (Programming Slope Compensation)

- \( V_{\text{SLP}} = \frac{I_{\text{SENSEP}}}{R_{\text{SLP}}} \)
- \( R_{\text{SLP}} = 0.2 \)
- \( R_{\text{SLP}} = 1.5 \times 10^3 \)
- \( R_{\text{SLP}} = 2 \times 10^3 \)

### OC Overcurrent (Hiccup Mode) Threshold vs Junction Temperature

For more information [www.analog.com](http://www.analog.com)
TYPICAL PERFORMANCE CHARACTERISTICS  \( T_A = 25^\circ C \), unless otherwise noted.

Extended Blanking Duration vs Junction Temperature

AOUT to OUT Delay (\( t_{AO} \)) and OUT to AOUT Delay (\( t_{OA} \)) vs Junction Temperature

AOUT to SOUT Delay (\( t_{AS} \)) vs Junction Temperature

SOUT (Fall) to OUT (Rise) Delay (\( t_{SO} = t_{AO} - t_{AS} \)) vs Junction Temperature

OUT (Fall) to SOUT (Rise) Delay (\( t_{OS} \)) vs Junction Temperature

AOUT to SOUT Delay (\( t_{AS} \)) vs Junction Temperature

Required \( R_{VSEC} \) vs Switching Frequency (for \( D_{VSEC} \times 100 = 72.5\% \), \( UVLO_{VSEC} = 1.25V \))

OUT Pin Rise/Fall Times vs OUT Pin Load Capacitance

For more information www.analog.com
PIN FUNCTIONS

**TEST1 (Pin 1):** Connect to GND.

**NC (Pins 2, 15, 16, 34, 37):** No Connect Pins. These pins are not connected inside the IC. These pins should be left open.

**RT (Pin 3):** A resistor to ground programs switching frequency.

**FB (Pin 4):** Error Amplifier Inverting Input.

**COMP (Pin 5):** Error Amplifier Output. Allows various compensation networks for nonisolated applications.

**SYNC (Pin 6):** Allows synchronization of internal oscillator to an external clock. \( f_{SYNC} \) equal to \( f_{OSC} \) allowed.

**SS1 (Pin 7):** Capacitor controls soft-start/stop of switching frequency and volt-second clamp. During soft-stop it also controls the COMP pin.

**IVSEC (Pin 8):** Resistor Programs OUT Pin Maximum Duty Cycle Clamp (\( DV_{SEC} \)). This clamp moves inversely proportional to system input voltage to provide a volt-second clamp.

**UVLO \( V_{SEC} \) (Pin 9):** A resistor divider from system input allows switch maximum duty cycle to vary inversely proportional with system input. This volt-second clamp prevents transformer saturation for duty cycles above 50%. Resistor divider ratio programs undervoltage lockout (UVLO) threshold. A 5µA pin current hysteresis allows programming of UVLO hysteresis. Pin below 0.4V reduces \( V_{IN} \) currents to microamps.

**OVLO (Pin 10):** A resistor divider from system input programs overvoltage lockout (OVLO) threshold. Fixed hysteresis included.

**TAO (Pin 11):** A resistor programs nonoverlap timing between AOUT rise and OUT rise control signals.

**TAS (Pin 12):** Resistors at \( T_{AO} \) and \( T_{AS} \) define delay between SOUT fall and OUT rise (= \( t_{AO} - t_{AS} \)).

**TOS (Pin 13):** Resistor programs delay between OUT fall and SOUT rise.

**TBLNK (Pin 14):** Resistor programs extended blanking of \( I_{ENSEP} \) and OC signals during MOSFET turn-on.

**SS2 (Pin 17):** Capacitor controls soft-start of COMP pin. Alternatively can connect to OPTO to communicate start of switching to secondary side. If unused, leave the pin open.

**GND (Pin 18):** Analog Signal Ground. Electrical connection exists inside the IC to the exposed pad (Pin 39).

**PGND (Pins 19, 38, 39):** The Power Grounds for the IC. The package has an exposed pad (Pin 39) underneath the IC which is the best path for heat out of the package. Pin 39 should be soldered to a continuous copper ground plane under the device to reduce die temperature and increase the power capability of the LT3753.

**I\( S\)ENSE (Pin 20):** Negative input for the current sense comparator. Kelvin connect to the sense resistor in the source of the power MOSFET.

**I\( S\)ENSEP (Pin 21):** Positive input for the current sense comparator. Kelvin connect to the sense resistor in the source of the power MOSFET. A resistor in series with \( I_{S}\)ENSEP programs slope compensation.

**OC (Pin 22):** An accurate 96mV threshold, independent of duty cycle, for detection of primary side MOSFET over-current and trigger of hiccup mode. Connect directly to sense resistor in the source of the primary side MOSFET.

**Missing Pins 23, 25, 27, 29, 31, 33, 35:** Pins removed for high voltage spacings and improved reliability.

**OUT (Pin 24):** Drives the gate of an N-channel MOSFET between 0V and \( INTVCC \). Active pull-off exists in shutdown.

**INTVCC (Pin 26):** A linear regulator supply generated from \( V_{IN} \). Supplies 10V for AOUT, SOUT and OUT gate drivers. \( INTVCC \) must be bypassed with a 4.7µF capacitor to power ground. Can be externally driven by the housekeeping supply to remove power from within the IC.

**\( V_{IN} \) (Pin 28):** Input Supply Pin. Bypass with 1µF to ground.

**SOUT (Pin 30):** Sync signal for secondary side synchronous rectifier controller.

**AOUT (Pin 32):** Control signal for external active clamp switch.

**TEST2 (Pin 36):** Connect to GND.
Figure 1. Timing Diagram

Figure 2. Timing Reference Circuit
Figure 3. Start-Up and Shutdown Timing Diagram
**LT3753**

**OPERATION**

**Introduction**

The LT3753 is a primary side, current mode, PWM controller optimized for use in a synchronous forward converter with active clamp reset. The LT3753 allows $V_{IN}$ pin operation between 8.5V and 100V. The LT3753 based forward converter is targeted for power levels up to 400W and is not intended for battery charger applications. For higher power levels the converter outputs can be stacked in series.

Connecting UVLO_VSEC pins, OVLO pins, SS1 pins and SS2 pins together allows blocks to react simultaneously to all fault modes and conditions.

The IC contains an accurate programmable volt-second clamp. When set above the natural duty cycle of the converter, it provides a duty cycle guardrail to limit primary switch reset voltage and prevent transformer saturation during load transients. The accuracy and excellent line regulation of the volt-second clamp provides $V_{OUT}$ regulation for open-loop conditions such as no opto-coupler, reference or error amplifier on the secondary side.

For applications not requiring isolation but requiring high step-down ratios, each IC contains a voltage error amplifier to allow a very simple nonisolated, fully regulated synchronous forward converter.

A range of protection features include programmable overcurrent (OC) hiccup mode, programmable system input undervoltage lockout (UVLO), programmable system input overvoltage lockout (OVLO) and built-in thermal shutdown. Programmable slope compensation and switching frequency allow the use of a wide range of output inductor values and transformer sizes.

**Part Start-Up**

LT3753 start-up is best described by referring to the Block Diagram and to the start-up waveforms in Figure 3. For part start-up, system input voltage must be high enough to drive the UVLO_VSEC pin above 1.25V and the $V_{IN}$ pin must be greater than 8.5V. An internal linear regulator is activated and provides a 10V INTVCC supply for all gate drivers. The SS1 pin of the forward controller is allowed to start charging when INTVCC reaches its 7V UVLO(+) threshold. When SS1 reaches 1.25V, the SS2 pin begins to charge, controlling COMP pin rise and the soft-start of output inductor peak current. The SS1 pin independently soft starts switching frequency and a volt-second clamp from 22% of their full-scale programmed values.

If secondary side control already exists for soft starting the converter output voltage then the SS2 pin can still be used to control initial inductor peak current rise. Simply programming the primary side SS2 soft-start faster than the secondary side allows the secondary side to take over. If SS2 is not needed for soft-start control, its pull-down strength and voltage rating also allow it to drive the input of an opto-coupler connected to INTVCC. This allows the option of communicating to the secondary side that switching has begun.
Applications Information

Programming System Input Undervoltage Lockout (UVLO) Threshold and Hysteresis

The LT3753 has an accurate 1.25V shutdown threshold at the UVLO_VSEC pin. This threshold can be used in conjunction with an external resistor divider to define the falling undervoltage lockout threshold (UVLO(–)) for the converter’s system input voltage (V_S) (Figure 4). A pin hysteresis current of 5µA allows programming of the UVLO(+) threshold.

\[
V_S (\text{UVLO}(–)) \text{ [begin SOFT-STOP then shut down]} \quad \text{= } 1.25 \cdot \left( 1 + \frac{R1}{R2+R3} \right)
\]

\[
V_S (\text{UVLO}(+)) \text{ [begin SOFT-START]} \quad \text{= } V_S (\text{UVLO}(–)) + (5\mu\text{A} \cdot R1)
\]

It is important to note that the part enters soft-stop when the UVLO_VSEC pin falls back below 1.25V. During soft-stop the converter continues to switch as it folds back switching frequency, volt-second clamp and COMP pin voltage. See Soft-Stop in the Applications Information section. When the SS2 pin is finally discharged below its 150mV reset threshold the forward converter is shut down.

Soft-Stop Shutdown

Soft-stop shutdown (similar to system undervoltage) can be commanded by an external control signal. A MOSFET with a diode (or diodes) in series with the drain should be used to pull down the UVLO_VSEC pin below 1.25V but not below the micropower shutdown threshold of 0.6V(max). Typical V_IN quiescent current after soft-stop is 165µA.

Micropower Shutdown

If a micropower shutdown is required using an external control signal, an open-drain transistor can be directly connected to the UVLO_VSEC pin. The LT3753 has a micropower shutdown threshold of typically 0.4V at the UVLO_VSEC pin. V_IN quiescent current in micropower shutdown is 20µA.

Programming System Input Overvoltage Lockout (OVLO) Threshold

The LT3753 has an accurate 1.25V overvoltage shutdown threshold at the OVLO pin. This threshold can be used in conjunction with an external resistor divider to define the rising overvoltage lockout threshold (OVLO(+)) for the converter’s system input voltage (V_S) (Figure 5). When OVLO(+) is reached, the part stops switching immediately and a hard stop discharges the SS1 and SS2 pins. The falling threshold OVLO(–) is fixed internally at 1.215V and allows the part to restart in soft-start mode. A single resistor divider can be used from system input supply (V_S) to define both the undervoltage and overvoltage thresholds for the system. Minimum value for R3 is 1k. If OVLO is unused, place a 10k resistor from OVLO pin to ground.

\[
V_S \text{ OVLO}(+) \text{ [stop switching; HARD STOP]} \quad \text{= } 1.25 \cdot \left( 1 + \frac{R1+R2}{R3} \right)
\]

\[
V_S \text{ OVLO}(–) \text{ [begin SOFT-START]} \quad \text{= } V_S \text{ OVLO}(+) \cdot \frac{1.215}{1.25}
\]
Programming Switching Frequency

The switching frequency for the LT3753 is programmed using a resistor, $R_T$, connected from analog ground (Pin 18) to the RT pin. Table 1 shows typical $f_{OSC}$ vs $R_T$ resistor values. The value for $R_T$ is given by:

$$R_T = 8.39 \cdot X \cdot (1 + Y)$$

where,

$$X = \frac{10^9}{f_{OSC}} - 365$$
$$Y = \frac{(300kHz - f_{OSC})}{10^7} \quad (f_{OSC} < 300kHz)$$
$$Y = \frac{(f_{OSC} - 300kHz)}{10^7} \quad (f_{OSC} > 300kHz)$$

Example: For $f_{OSC} = 200kHz$,

$$R_T = 8.39 \cdot 4635 \cdot (1 + 0.01) = 39.28k \ (\text{choose } 39.2k)$$

The LT3753 includes frequency foldback at start-up (see Figure 3). In order to make sure that a SYNC input does not override frequency foldback during start-up, the SYNC function is ignored until SS1 pin reaches 2.2V.

Table 1. $R_T$ vs Switching Frequency ($f_{OSC}$)

<table>
<thead>
<tr>
<th>SWITCHING FREQUENCY (kHz)</th>
<th>$R_T$ (kΩ)</th>
</tr>
</thead>
<tbody>
<tr>
<td>100</td>
<td>82.5</td>
</tr>
<tr>
<td>150</td>
<td>53.6</td>
</tr>
<tr>
<td>200</td>
<td>39.2</td>
</tr>
<tr>
<td>250</td>
<td>30.9</td>
</tr>
<tr>
<td>300</td>
<td>24.9</td>
</tr>
<tr>
<td>350</td>
<td>21</td>
</tr>
<tr>
<td>400</td>
<td>18.2</td>
</tr>
<tr>
<td>450</td>
<td>15.8</td>
</tr>
<tr>
<td>500</td>
<td>14</td>
</tr>
</tbody>
</table>

Synchronizing to an External Clock

The LT3753 internal oscillator can be synchronized to an external clock at the SYNC pin. SYNC pin high level should exceed 1.8V for at least 100ns and SYNC pin low level should fall below 0.6V for at least 100ns. The SYNC pin frequency should be set equal to or higher than the typical frequency programmed by the RT pin. An $f_{SYNC}/f_{OSC}$ ratio of $x \ (1.0 < x < 1.25)$ will reduce the externally programmed slope compensation by a factor of 1.2$x$. If required, the external resistor $R_{ISLP}$ can be reprogrammed higher by a factor of 1.2$x$. (see Current Sensing and Programmable Slope Compensation).

During soft-start the SYNC input is ignored until SS1 exceeds 2.2V. During soft-stop the SYNC input is completely ignored. If the SYNC input is to be used, recall that the programmable duty cycle clamp $D_{VSEC}$ is dependent on the switching frequency of the part (see section Programming Duty Cycle Clamp). $R_{IVSEC}$ should be reprogrammed by $1/x$ for an $f_{SYNC}/f_{OSC}$ ratio of $x$.

INTVCC Regulator Bypassing and Operation

The INTVCC pin is the output of an internal linear regulator driven from $V_{IN}$ and provides a 10V supply for onboard gate drivers AOUT, SOUT and OUT. INTVCC should be bypassed with a 4.7μF low ESR, X7R or X5R ceramic capacitor to power ground to ensure stability and to provide enough charge for the gate drivers.

The INTVCC regulator has a minimum 19mA output current limit. This current limit should be considered when choosing the switching frequency and capacitance loading on each gate driver. Average current load on the INTVCC pin for a single gate driver driving an external MOSFET is given as:

$$I_{INTVCC} = f_{OSC} \cdot Q_G$$
APPLICATIONS INFORMATION

where:

\[ f_{OSC} = \text{controller switching frequency} \]
\[ Q_G = \text{gate charge} \ (V_{GS} = \text{INTVCC}) \]

While the INTVCC 19mA output current limit is sufficient for LT3753 applications, efficiency and internal power dissipation should also be considered. INTVCC can be externally overdriven by an auxiliary supply (see Generating Auxiliary Supplies in the Applications Information section) to improve efficiency, remove power dissipation from within the IC and provide more than 19mA output current capability. Any overdrive level should exceed the regulated INTVCC level but not exceed 16V.

In the case of a short-circuit fault from INTVCC to ground, the IC reduces the INTVCC output current limit to typically 13mA. The INTVCC regulator has an undervoltage lockout rising threshold, UVLO(+), which prevents gate driver switching until INTVCC reaches 7V and maintains switching until INTVCC falls below a UVLO(−) threshold of 6.8V.

For \( V_{IN} \) levels close to or below the INTVCC regulated level, the INTVCC linear regulator may enter dropout. The resulting lower INTVCC level will still allow gate driver switching as long as INTVCC remains above INTVCC UVLO(−) levels. See the Typical Performance Characteristics section for INTVCC performance vs \( V_{IN} \) and load current.

Adaptive Leading Edge Blanking Plus Programmable Extended Blanking

The LT3753 provides a ±2A gate driver at the OUT pin to control an external N-channel MOSFET for main power delivery in the forward converter (Figure 7). During gate rise time and sometime thereafter, noise can be generated in the current sensing resistor connected to the source of the MOSFET. This noise can potentially cause a false trip of sensing comparators resulting in early switch turn off and in some cases re-soft-start of the system. To prevent this, LT3753 provides adaptive leading edge blanking of both OC and ISENSEP signals to allow a wide range of MOSFET \( Q_G \) ratings. In addition, a resistor \( R_{TBLNK} \) connected from \( T_{BLNK} \) pin to analog ground (Pin 18) programs an extended blanking duration (Figure 6).

Adaptive leading edge blanking occurs from the start of OUT rise and completes when OUT reaches within 1V of its maximum level. An extended blanking then occurs which is programmable using the \( R_{TBLNK} \) resistor given by:

\[
t_{BLNK} = 50\text{ns} + \left( \frac{2.2\text{ns}}{k} \right) \cdot R_{TBLNK} ,
\]

\[ 7.32k < R_{TBLNK} < 249k \]

Adaptive leading edge blanking minimizes the value required for \( R_{TBLNK} \). Increasing \( R_{TBLNK} \) further than required increases M1 minimum on time (Figure 7).

In addition, the critical volt-second clamp (\( D_{VSEC} \)) is not blanked. Therefore, if \( D_{VSEC} \) decreases far enough (in soft start foldback and at maximum input voltage) M1 may turn off before blanking has completed. Since OC and ISENSEP signals are only seen when M1 is on (and after blanking has completed), \( R_{TBLNK} \) value should be limited by:

\[
(2.2\text{ns}/k)R_{TBLNK} < T_{VSEC(MIN)} - t_{ADAPTIVE} - 50\text{ns}
\]
where,

\[ T_{VSEC(MIN)} = 10^9\left(\frac{D_{VSEC(MAX)}}{fold \cdot fosc}\right) \]

\[ \cdot \left(\frac{Input_{MIN}/Input_{MAX}}{fold}\right) \]

\[ fold = \frac{f_{OSC}}{D_{VSEC}} \text{ foldback ratio (for OUT pin)} \]

\[ t_{ADAPTIVE} = \text{OUT pin rise time to INTVCC} - 1V \]

Example: For Figure 22 circuit, \( D_{VSEC(MAX)} = 0.77 \), \( \frac{Input_{MIN}/Input_{MAX}}{fold} = 4 \), \( t_{ADAPTIVE} = 23\text{ns} \) and \( f_{OSC} = 240\text{kHz} \),

\[ T_{VSEC(MIN)} = 10^9\left(\frac{0.77}{4 \cdot 2.4 \cdot 10^5}\right) \cdot 17.4/74 = 188\text{ns} \]

(2.2\text{ns}/1k)\( R_{BLNK} < 188 - 23 - 50 \)

\[ R_{BLNK} < 52.5\text{k} \text{ (Actual Circuit Uses 34k)} \]

**Current Sensing and Programmable Slope Compensation**

The LT3753 commands cycle-by-cycle peak current in the external switch and primary winding of the forward transformer by sensing voltage across a resistor connected in the source of the external n-channel MOSFET (Figure 7).

The sense voltage across \( R_{SENSE} \) is compared to a sense threshold at the \( I_{SENSEP} \) pin, controlled by COMP pin level. Two sense inputs, \( I_{SENSEP} \) and \( I_{SENSEN} \), are provided to allow a Kelvin connection to \( R_{SENSE} \). For operation in continuous mode and above 50% duty cycle, required slope compensation can be programmed by adding a resistor, \( R_{ISLP} \), in series with the \( I_{SENSEP} \) pin. A ramped current always flows out of the \( I_{SENSEP} \) pin. The current starts from 2\( \mu \)A at 0% duty cycle and linearly ramps to 33\( \mu \)A at 80% duty cycle. A good starting value for \( R_{ISLP} \) is 1.5k\( \Omega \) which gives a 41mV total drop in current comparator threshold at 65% duty cycle.

The COMP pin commands an \( I_{SENSEP} \) threshold between 0mV and 220mV. The 220mV allows a large slope compensation voltage drop to exist in \( R_{ISLP} \) without effecting the programming of \( R_{SENSE} \) to set maximum operational currents in M1. An \( t_{SYNC}/f_{OSC} \) ratio of \( x \) (1.0 < \( x < 1.25 \)) will reduce the externally programmed slope compensation by a factor of 1.2x. If required, the external resistor \( R_{ISLP} \) can be reprogrammed higher by a factor of 1.2x.

**Overcurrent: Hiccup Mode**

The LT3753 uses a precise 96mV sense threshold at the OC pin to detect excessive peak switch current (Figure 7). During an overload condition switching stops immediately and the SS1/SS2 pins are rapidly discharged. The absence of switching reduces the sense voltage at the OC pin, allowing SS1/SS2 pins to recharge and eventually attempt switching again. The part exists in this hiccup mode as long as the overcurrent condition exists. This protects the converter and reduces power dissipation in the components (see Hard Stop in the Applications Information section). The 96mV peak switch current threshold is independent of the voltage drop in \( R_{ISLP} \) used for slope compensation.

Output DC load current to trigger hiccup mode:

\[ I_{LOAD(OVERCURRENT)} = \left(\frac{N_P}{N_S} \cdot \frac{96\text{mV}}{R_{ISENSE}}\right) - \left(\frac{1}{2} I_{RIPPLE(P-P)}\right) \]

where:

\( N_P = \) forward transformer primary turns

\( N_S = \) forward transformer secondary turns

\( I_{RIPPLE(P-P)} = \) Output inductor peak-to-peak ripple current

\( R_{ISENSE} \) should be programmed to allow maximum DC load current for the application plus enough margin during load transients to avoid overcurrent hiccup mode.

**Programming Maximum Duty Cycle Clamp: DVSEC (Volt-Second Clamp)**

Unlike other converters which only provide a fixed maximum duty cycle clamp, the LT3753 provides an accurate programmable maximum duty cycle clamp (\( D_{VSEC} \)) on the OUT pin which moves inversely with system input. \( D_{VSEC} \) provides a duty cycle guardrail to limit the volt-seconds-on product over the entire
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natural duty cycle range (Figures 8 and 9). This limits the drain voltage required for complete transformer reset. A resistor \( R_{IVSEC} \) from the IVSEC pin to analog ground (Pin 18) programs \( DVSEC \).

\[
DVSEC = \text{(OUT pin duty cycle clamp)}
\]

\[
= 0.725 \times \frac{R_{IVSEC} \times f_{OSC}}{51.1k \times 300 \times \text{UVLO}_VSEC} \times 1.25
\]

where:

\( R_{IVSEC} \) = programming resistor at IVSEC pin

\( f_{OSC} \) = switching frequency (kHz)

\( \text{UVLO}_VSEC \) = resistor divided system input voltage

\( R_{IVSEC} \) can program any \( DVSEC \) required at minimum system input. \( DVSEC \) will then follow natural duty cycle as \( V_{IN} \) varies. Maximum programmable \( DVSEC \) is typically 0.75 but may be further limited by the transformer design and voltage ratings of components connected to the drain of the primary side power MOSFET (SWP). See voltage calculations in the LO side and HI side active clamp topologies sections.

If system input voltage falls below it’s UVLO threshold the part will enter soft-stop with continued switching. The LT3753 includes an intelligent circuit which prevents \( DVSEC \) from continuing to rise as system input voltage falls (see Soft-Stop). Without this, too large a \( DVSEC \) would require extremely high reset voltages on the SWP node to properly reset the transformer. The \( \text{UVLO}_VSEC \) pin maximum operational level is the lesser of \( V_{IN} - 2V \) or 12.5V.

The LT3753 volt-second clamp architecture is superior to an external RC network connected from system input to trip an internal comparator threshold. The RC method suffers from external capacitor error, part-to-part mismatch between the RC time constant and the IC’s switching period, the error of the internal comparator threshold and the nonlinearity of charging at low input voltages. The LT3753 uses the \( R_{IVSEC} \) resistor to define the charge current for an internal timer capacitor to set an OUT pin maximum on-time, \( t_{ON(VSEC)} \). The voltage across \( R_{IVSEC} \) follows \( \text{UVLO}_VSEC \) pin voltage (divided down from system input voltage). Hence, \( R_{IVSEC} \) current varies linearly with input supply. The LT3753 also trims out internal timing capacitor and comparator threshold errors to optimize part-to-part matching between \( t_{ON(VSEC)} \) and \( T \).

\( DVSEC \) Open Loop Control: No Opto-Coupler, Error Amplifier or Reference

The accuracy of the programmable volt-second clamp (\( DVSEC \)) safely controls \( V_{OUT} \) if open loop conditions exist such as no opto-coupler, error amplifier or reference on the secondary side. \( DVSEC \) controls the output of the converter by controlling duty cycle inversely proportional to system input. If \( DVSEC \) duty cycle guardrail is programmed \( X \% \) above natural duty cycle, \( V_{OUT} \) will only increase by \( X \% \) if a closed loop system breaks open. This volt-second clamp is operational over a 10:1 system input voltage range. See \( DVSEC \) versus \( \text{UVLO}_VSEC \) pin voltage in the Typical Performance Characteristics section.

\( R_{IVSEC} \): Open Pin Detection Provides Safety

The LT3753 provides an open-detection safety feature for the \( R_{IVSEC} \) pin. If the \( R_{IVSEC} \) resistor goes open circuit the part immediately stops switching. This prevents the part from running without the volt-second clamp in place.
Transformer Reset: Active Clamp Technique

The LT3753 includes a ±0.4A gate driver at the AOUT pin to allow the use of an active clamp transformer reset technique (Figures 10, 14). The active clamp method improves efficiency and reduces voltage stress on the main power switch, M1. By switching in the active clamp capacitor only when needed, the capacitor does not lose its charge during M1 on-time. By allowing the active clamp capacitor, CCL, to store the average voltage required to reset the transformer, the main power switch sees lower drain voltage.

In addition, the active clamp drain waveform on M1 (Figure 11) allows a self-driven architecture, whereby the drains of M3 and M4 drive the gates of M4 and M3 respectively, removing the need for a secondary-side synchronous MOSFET driver (Figure 21). In a self-driven architecture, the reset voltage level on M1, VOUT level and duty cycle range (governed by system input range) must be considered to ensure the maximum VGS rating of synchronous MOSFETs M3, M4 are not exceeded.

An imbalance of volt-seconds will cause magnetizing current to walk upwards or downwards until the active clamp capacitor is charged to the optimal voltage for proper transformer reset. The voltage rating of the capacitor will depend on whether the active clamp capacitor is actively switched to ground (Figure 10) or actively switched to system input (Figure 14). In an active clamp reset topology, volt-second balance requires:

\[ V_{IN} \cdot D = (SWP - V_{IN}) \cdot (1 - D) \]

where:

- \( V_{IN} \) = Transformer input supply
- \( D = (V_{OUT}/V_{IN}) \cdot N \) = switch M1 duty cycle
- \( V_{OUT} \) = Output voltage (including the voltage drop contribution of M4 catch diode during M1 off)
- \( N = \) Transformer turns ratio = NP/NS
- \( SWP = \) M1 drain voltage

**LO Side Active Clamp Topology (LT3753)**

The steady-state active clamp capacitor voltage, \( V_{CCL} \), required to reset the transformer in a LO side active clamp topology (Figure 10) can be approximated as the drain-to-source voltage (\( V_{DS} \)) of switch M1, given by:

\[ V_{CCL} (\text{LO side}): \]

(a) Steady state: \( V_{CCL} = SWP = V_{DS} \)

\[ = \left( \frac{1}{1 - D} \right) \cdot V_{IN} = \frac{V_{IN}^2}{V_{IN} - (V_{OUT} \cdot N)} \]

(b) Transient:

During load transients, duty cycle and hence \( V_{CCL} \) may increase. Replace D with DVSEC in the equation above to calculate transient \( V_{CCL} \) values. See the previous section Programming Duty Cycle Clamp–DVSEC. The DVSEC guardrail can be programmed as close as 5% higher than D but may require a larger margin to improve transient response.
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As shown in Figure 12, the maximum steady-state value for \( V_{\text{CCL}} \) may occur at minimum or maximum input voltage. Hence \( V_{\text{CCL}} \) should be calculated at both input voltage levels and the largest of the two calculations used. M1 drain should be rated for a voltage greater than the above steady-state \( V_{\text{DS}} \) calculation due to tolerances in duty cycle, load transients, voltage ripple on \( C_{\text{CL}} \) and leakage inductance spikes. \( C_{\text{CL}} \) should be rated higher due to the effect of voltage coefficient on capacitance value. A typical choice for \( C_{\text{CL}} \) is a good quality X7R capacitor. M2 should have a \( V_{\text{DS}} \) rating greater than \( V_{\text{CCL}} \) since the bottom plate of \( C_{\text{CL}} \) is \(-V_{\text{CCL}}\) during M1 on and M2 off. For high input voltage applications, the limited \( V_{\text{DS}} \) rating of available P-channel MOSFETs might require changing from a LO side to HI side active clamp topology.

For the LO side active clamp topology in steady state, during M1 on time, magnetizing current \((I_{\text{MAG}})\) increases from a negative value to a positive value (Figure 11). When M1 turns off, magnetizing current charges SWP until it reaches \( V_{\text{CCL}} \) plus the voltage drop of the M2 body diode. At this point SWP becomes a positive voltage. (Figure 12).

For the HI side active clamp topology in steady state, during M1 on time, magnetizing current \((I_{\text{MAG}})\) increases from a negative value to a positive value (Figure 13). When M1 turns off, magnetizing current charges SWP until it reaches \( V_{\text{CCL}} \) plus the voltage drop of the M2 body diode. At this point SWP becomes a positive voltage.
moment the active clamp capacitor is passively switched in to ground (due to the forward conduction of M2 body diode) and the drain voltage increases at a slower rate due to the loading of CCL. SWP above VIN causes IMAG to reduce from a positive value towards zero (dVSWP/dT = 0). As IMAG becomes negative it begins to discharge the SWP node. Switching in M2 before IMAG reverses, actively connects the bottom plate of CCL to ground and allows SWP to be discharged slowly. The resulting SWP waveform during M1 off-time appears as a square wave with a superimposed sinusoidal peak representing ripple voltage on CCL.

The switch M2 experiences near zero voltage switching (ZVS) since only the body diode voltage drop appears across it at switch turn on.

HI Side Active Clamp Topology (LT3752-1)

For high input voltage applications the VDS rating of available P-channel MOSFETs might not be high enough to be used as the active clamp switch in the LO side active clamp topology (Figure 10). An N-channel approach using the HI side active clamp topology (Figure 14) should be used. (The LT3752-1 is ideal for the HI side active clamp topology). This topology requires a gate drive transformer or a simple gate drive opto-coupler to drive the N-channel MOSFET (M2) for switching in the active clamp capacitor from SWP to VIN. The M1 drain voltage calculation is the same as in the LO side active clamp case and M1 should be rated in a similar manner. The voltage across the clamp capacitor in the HI side architecture, however, is lower by VIN since it is referenced to VIN.

The steady-state active clamp capacitor voltage V_CCL to reset the transformer in a HI side active clamp topology can be approximated by:

\[ V_{CCL} (HI \ side): \]

(a) Steady state: \[ V_{CCL} = V_{RESET} = V_{DS} - V_{IN} \]
\[ = \left( \frac{D}{1-D} \right) \cdot V_{IN} = V_{IN} \cdot V_{OUT} \cdot \frac{N}{V_{IN} - (V_{OUT} \cdot N)} \]

(b) Transient:

During load transients, duty cycle and hence \( V_{CCL} \) may increase. Replace \( D \) with \( D_{VSEC} \) in the equation above to calculate transient \( V_{CCL} \) values. \( D_{VSEC} \) guardrail can be programmed as close as 6% higher than \( D \) but may require a larger margin to improve transient response. See the previous section Programming Duty Cycle Clamp–\( D_{VSEC} \).

\( C_{CL} \) should be rated for a voltage higher than the above steady-state calculation due to tolerances in duty cycle, load transients, voltage ripple on \( C_{CL} \) and the effect of voltage coefficient on capacitance value. A typical choice for \( C_{CL} \) is a good quality (X7R) capacitor. When using a gate drive transformer to provide control of the active clamp switch (M2), the external components C1, C2, R1, D1 and T4 are required. T4 size will increase for lower programmed switching frequencies due to a minimum volt-second requirement. Alternatively, a simple gate driver opto-coupler can be used as a switch to control M2, for a smaller solution size.

Active Clamp Capacitor Value and Voltage Ripple

The active clamp capacitor value should be chosen based on the amount of voltage ripple which can be tolerated by components attached to SWP. Lower \( C_{CL} \) values will create larger voltage ripple (increased drain voltage for the primary side power MOSFET) but will require less swing in magnetizing current to move the active clamp capacitor during duty cycle changes. Choosing too high a value for the active clamp capacitor (beyond what is needed to keep ripple voltage to an acceptable level) will require unnecessary additional flux swing during transient conditions. For systems with flux swing detection, too high a value for the active clamp capacitor will trigger the detection system early and degrade transient response.

Another factor to consider is the resonance between \( C_{CL} \) and the magnetizing inductance \( (L_{MAG}) \) of the main transformer. An RC snubber \( (R_S, C_S) \) in parallel with \( C_{CL} \) will dampen
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the sinusoidal ringing and limit the peak voltages at the primary side MOSFET drain during input/load transients. Check circuit performance to determine if the snubber is required. Component values can be approximated as:

\[ C_{CL} = \frac{10}{L_{MAG}} \left( \frac{1-D_{MIN}}{2 \pi f_{OSC}} \right)^2 \]

where,

\[ D_{MIN} = \frac{V_{OUT}}{V_{IN(MAX)}} \cdot \frac{N_P}{N_S} \]

and (if needed),

\[ C_S = 6 \cdot C_{CL} \]

\[ R_S = \frac{1}{(1-D_{MAX})} \cdot \sqrt{\frac{L_{MAG}}{C_{CL}}} \]

where,

\[ D_{MAX} = \frac{V_{OUT}}{V_{IN(MIN)}} \cdot \frac{N_P}{N_S} \]

Check the voltage ripple on SWP during steady-state operation.

\[ V_{CCL(ripples)} = V_{CCL} \cdot (1-D)^2/(8 \cdot C_{CL} \cdot L_{MAG} \cdot f_{OSC}^2) \]

where,

\[ D = \frac{V_{OUT}}{V_{IN}} \cdot \frac{N_P}{N_S} \]

\[ V_{CCL} = V_{IN}/(1-D) \] (Lo side active clamp topology)

\[ V_{CCL} = D \cdot V_{IN}/(1-D) \] (Hi side active clamp topology)

Example : For \( V_{IN} = 36V \), \( V_{OUT} = 12V \), \( N_P/N_S = 2 \), \( V_{CCL} = 108V \) (Lo side active clamp topology), \( C_{CL} = 22nF \), \( L_{MAG} = 100\mu H \), \( f_{OSC} = 250kHz \), \( V_{CCL(ripples)} = 108(0.33)^2/(8(22 \cdot 10^{-9})(2.5 \cdot 10^5)^2) = 10.7V \)

The transformer is typically chosen to operate at a maximum flux density that is low enough to avoid excessive core losses. This also allows enough headroom during input and load transients to move the active clamp capacitor at a fast enough rate to keep up with duty cycle changes.

Active Clamp MOSFET Selection

The selection of active clamp MOSFET is determined by the maximum levels expected for the drain voltage and drain current. The active clamp switch (M2) in either a lo side or hi side active clamp topology has the same BVdss requirements as the main N-channel power MOSFET. The current requirements are divided into two categories :

(A) Drain Current

This is typically less than the main N-channel power MOSFET because the active clamp MOSFET sees only magnetizing current, estimated as :

\[ \text{Peak } I_{MAG} \text{ (steady state)} = \frac{1}{2} \cdot (N_P/N_S) \cdot \frac{V_{OUT}}{L_{MAG} \cdot f_{OSC}} \]

(B) Body Diode Current

The body diode will see reflected output current as a pulse every time the main N-channel power MOSFET turns off. This is due to residual energy stored in the transformer’s leakage inductance. The body diode of the active clamp MOSFET should be rated to withstand a forward pulsed current of:

\[ I_{D(MAX)} = (N_S/N_P) \cdot (I_{OUT(MAX)} + (I_{L(ripples)}(P-P)/2)) \]

where,

\[ I_{L(ripples)}(P-P) = \text{output inductor ripple current} = \frac{V_{OUT}/(L_{OUT} \cdot f_{OSC})}{(1-(V_{OUT}/V_{IN})(N_P/N_S))} \]

\[ I_{OUT(MAX)} = \text{maximum output load current} \]
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Programming Active Clamp Switch Timing: AOUT to OUT (t_{AO}) and OUT to AOUT (t_{OA}) Delays

The timings t_{AO} and t_{OA} represent the delays between AOUT and OUT edges (Figures 1 and 2) and are programmed by a single resistor, R_{TAO}, connected from analog ground (Pin 18) to the T_{AO} pin. Once t_{AO} is programmed for the reasons given below, t_{OA} will be automatically generated.

Front-end timing t_{AO} (M2 off, M1 on)

\[ = \text{AOUT}(\text{edge})-\text{to-OUT}(\text{rising}) \]
\[ = 50\text{ns} + 3.8\text{ns} \cdot \left(\frac{R_{TAO}}{1k}\right), 14.7 < R_{TAO} < 125k \]

In order to minimize turn-on transition loss in M1 the drain of M1 should be as low as possible before M1 turns on. To achieve this, AOUT should turn M2 off a delay of t_{AO} before OUT turns M1 on. This allows the main transformer’s magnetizing current to discharge M1 drain voltage quickly towards \(V_{IN}\) before M1 turns on.

As SWP falls below \(V_{IN}\), however, the rectifying diodes on the secondary side are typically active and clamp the SWP node close to \(V_{IN}\). If enough leakage inductance exists, however, the clamping action on SWP by the secondary side will be delayed—potentially allowing the drain of M1 to be fully discharged to ground just before M1 turns on. Even with this delay due to the leakage inductance, \(L_{MAG}\) needs to be low enough to allow \(I_{MAG}\) to be negative enough to slew SWP down to ground before M1 turns on. If achievable, M1 will experience zero voltage switching (ZVS) for highest efficiency. As will be seen in a later section entitled Primary-Side Power MOSFET Selection, M1 transition loss is a significant contributor to M1 losses.

Back-end timing t_{OA} (M1 off, M2 on) is automatically generated

\[ = \text{OUT}(\text{falling})-\text{to-AOUT}(\text{edge}) = 0.9 \cdot t_{AO} \]

\(t_{OA}\) should be checked to ensure M2 is not turned on until M1 and M3 are turned off.

Programming Synchronous Rectifier Timing: SOUT to OUT (t_{SO}) and OUT to SOUT (t_{OS}) Delays

The LT3753 includes a ±0.4A gate driver at the SOUT pin to send a control signal via a pulse transformer to the secondary side of the forward converter for synchronous rectification (see Figures 1 and 2). For the highest efficiency, M4 should be turned on whenever M1 is turned off. This suggests that SOUT should be a non-overlapping signal with OUT with very small non-overlap times. Inherent timing delays, however, which can vary from application to application, can exist between OUT to CSW and between SOUT to CG. Possible shoot-through can occur if both M1 and M4 are on at the same time, resulting in transformer and/or switch damage.

Front-end timing: t_{SO} (M4 off, M1 on)

\[ = \text{SOUT}(\text{falling})-\text{to-OUT}(\text{rising}) \text{ delay} \]
\[ = t_{SO} = t_{AO} - t_{AS} \]
\[ = 3.8\text{ns} \cdot (R_{TAS} - R_{TAO}) \]

where:

\[ t_{AS} = 50\text{ns} + (3.8\text{ns} \cdot R_{TAS}/1k), 14.7k < R_{TAS} < 125k, \]
\[ t_{AO} = 50\text{ns} + (3.8\text{ns} \cdot R_{TAO}/1k), 14.7k < R_{TAO} < 125k, \]
\[ t_{SO} \text{ is defined by resistors } R_{TAS} \text{ and } R_{TAO} \text{ connected from analog ground (Pin 18) to their respective pins } T_{AS} \text{ and } T_{AO}. \text{ Each of these resistor defines a delay referenced to the AOUT edge at the start of each cycle. } R_{TAO} \text{ was already programmed based on requirements defined in the previous section Programming AOUT to OUT Delay. } \]
\[ R_{TAS} \text{ is then programmed as a delay from AOUT to SOUT to fulfill the equation above for } t_{SO}. \text{ By choosing } R_{TAS} \text{ less than or greater than } R_{TAO}, \text{ the delay between SOUT falling and OUT rising can be programmed as positive or negative. While a positive delay can always be programmed for } t_{SO}, \text{ the ability to program a negative delay allows for improved efficiency if OUT(rising)-to-CSW(rising) delay is larger than SOUT(falling)-to-CG(rising) delay.} \]

Back-end timing: t_{OS} (M1 off, M4 on)

\[ = \text{OUT}(\text{falling})-\text{to-SOUT}(\text{rising}) \text{ delay} \]
\[ = t_{OS} = 35\text{ns} + (2.2\text{ns} \cdot R_{TOS}/1k), 7.32k < R_{TOS} < 249k \]
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The timing resistor, \( R_{\text{RTOS}} \), defines the OUT (falling)-to-SOUT (rising) delay. This pin allows programming of a positive delay, for applications which might have a large inherent delay from OUT fall to SW2 fall.

Soft-Start (SS1, SS2)

The LT3753 uses SS1 and SS2 pins for soft starting various parameters (Figures 3 and 15). SS1 soft starts internal oscillator frequency and \( D_{\text{VSEC}} \) (maximum duty cycle clamp). SS2 soft starts COMP pin voltage to control output inductor peak current. Using separate SS1 and SS2 pins allows the soft-start ramp of oscillator frequency and \( D_{\text{VSEC}} \) to be independent of COMP pin soft-start. Typically SS1 capacitor \( (C_{SS1}) \) is chosen as 0.47\( \mu \)F and SS2 capacitor \( (C_{SS2}) \) is chosen as 0.1\( \mu \)F. Soft-start charge currents are 11.5\( \mu \)A for SS1 and 21\( \mu \)A for SS2.

SS1 is allowed to start charging (soft-start) if all of the following conditions exist (typical values):

1. \( \text{UVLO}_{\text{VSEC}} > 1.25V \): System input not in UVLO
2. \( \text{OVLO} < 1.215V \): System input not in OVLO
3. \( \text{OC} < 96\text{mV} \): No over current condition
4. \( 7V < \text{INTVCC} < 16V \): INTVCC valid
5. \( T_J < 165^\circ \text{C} \): Junction temperature valid
6. \( V_{\text{IN}} > 7.75V \): \( V_{\text{IN}} \) pin valid

SS1 = 0V to 1.25V (no switching). This is the SS1 range for no switching for the forward converter. SS2 = 0V.

SS1 > 1.25V allows SS2 to begin charging from 0V.

SS1 = 1.25V to 2.45V (soft-start \( f_{\text{OSC}}, D_{\text{VSEC}} \)). This is the SS1 range for soft-starting \( f_{\text{OSC}} \) and \( D_{\text{VSEC}} \) folded back from 22% to 100% of their programmed levels. Fold back of \( f_{\text{OSC}} \) and \( D_{\text{VSEC}} \) reduces effective minimum duty cycle for the primary side MOSFET. This allows inductor current to be controlled at low output voltages during start-up.

SS1 ramp rate is chosen slow enough to ensure \( f_{\text{OSC}} \) and \( D_{\text{VSEC}} \) foldback lasts long enough for the converter to take control of inductor current at low output voltages. In addition, slower SS1 ramp rate increases the non-switching period during an output short to ground fault (over current hiccup mode) to reduce average power dissipation (see Hard-Stop).

SS2 = 0V to 1.6V (soft-start COMP pin). This is the SS2 range for soft-starting COMP pin from approximately 1V to 2.6V.

SS2 ramp rate is chosen fast enough to allow a (slower) soft-start control of COMP pin from a secondary side opto-coupler controller.

SS1 soft-start non-switching period (0V to 1.25V) = 1.25V • \( C_{SS1}/11.5\mu\text{A} \)

SS1 soft-start \( f_{\text{OSC}}, D_{\text{VSEC}} \) period (1.25V to 2.45V) = 1.2V • \( C_{SS1}/11.5\mu\text{A} \)

SS2 soft-start COMP period (0V to 1.6V) = 1.6V • \( C_{SS2}/21\mu\text{A} \)

Soft-Stop (SS1)

The LT3753 gradually discharges the SS1 pin (soft-stop) when a system input UVLO occurs or when an external soft-stop shutdown command occurs (0.4V < \( \text{UVLO}_{\text{VSEC}} < 1.25V \)). During SS1 soft-stop the converter continues to switch, folding back \( f_{\text{OSC}}, D_{\text{VSEC}} \) and COMP pin voltage (Figures 3 and 15). Soft-stop discharge current is 10.5\( \mu \)A for SS1. Soft-stop provides:

1. Active control of the secondary winding during output discharge for clean shutdown in self-driven applications.
2. Controlled discharge of the active clamp capacitor to minimize magnetizing current swing during restart.

SS1: 2.45V to 1.25V (soft-stop \( f_{\text{OSC}}, D_{\text{VSEC}}, \text{COMP} \)). This is the SS1 range for soft-stop folding back of:

1. \( f_{\text{OSC}} \) and \( D_{\text{VSEC}} \) from 100% to 22% of their programmed levels.
2. COMP pin (100% to 0% of commanded peak current).

SS1 soft-stop \( f_{\text{OSC}}, D_{\text{VSEC}}, \text{COMP} \) period (2.45V to 1.25V) = 1.2V • \( C_{SS1}/10.5\mu\text{A} \)
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SS1 < 1.25V. Forward converter stops switching and SS2 pin is discharged to 0V using 2.8mA.
SS1 = 1.25V to 0V: When SS1 falls below 0.15V the internal SS1 latch is reset. If all faults are removed, SS1 begins charging again. If faults still remain, SS1 discharges to 0V.
SS1 soft-stop non-switching period (1.25V to 0V) = 1.25V • C_{SS1}/10.5µA

\( D_{VSEC} \) rises as system input voltage falls in order to provide a maximum duty cycle guardrail (volt-second clamp). When system input falls below it's UVLO threshold, however, this triggers a soft-stop with the converter continuing to switch. It is important that \( D_{VSEC} \) no longer increases even though system input voltage may still be falling. The LT3753 achieves an upper clamp on \( D_{VSEC} \) by clamping the minimum level for the \( V_{SEC} \) pin to 1.25V. As SS1 pin discharges during soft-stop it folds back \( D_{VSEC} \). As \( D_{VSEC} \) falls below the natural duty cycle of the converter, the converter loop follows \( D_{VSEC} \). If the system input voltage rises (\( V_{SEC} \) pin rises) during soft-stop the volt-second clamp circuit further reduces \( D_{VSEC} \). The I.C. chooses the lowest \( D_{VSEC} \) commanded by either the \( V_{SEC} \) pin or the SS1 soft-stop function.

### Hard-Stop (SS1, SS2)

Switching immediately stops and both SS1 and SS2 pins are rapidly discharged (Figure 15. Hard-Stop) if any of the following faults occur (typical values):

1. **UVLO_\_VSEC < 0.4V:** Micropower shutdown
2. **OVLO > 1.250V:** System input OVLO
3. **OC > 96mV:** Over current condition
4. **INTVCC < 6.8V (UVLO), > 16.5V (OVLO):**
5. **T_J > 170°C:** Thermal shutdown
6. **V_IN < 7.42:** V_IN pin UVLO

**Figure 15. SS1, SS2 and COMP Pin Voltages During Faults, Soft-Start and Soft-Stop**
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Switching stops immediately for any of the faults listed above. When SS1 discharges below 0.15V it begins charging again if all faults have been removed. For an over current fault triggered by OC > 96mV, the disable of switching will cause the OC pin voltage to fall back below 96mV. This will allow SS1 and SS2 to recharge and eventually attempt switching again. If the over current condition still exists, OC pin will exceed 96mV again and the discharge/charge cycle of SS1 and SS2 will repeat in a hiccup mode. The non-switching dead time period during hiccup mode reduces the average power seen by the converter in an over current fault condition. The dead time is dominated by SS1 recharging from 0.15V to 1.25V.

Non-switching period in over current (hiccup mode):
= 1.1V • C_{SS1}/11.5\mu A

OUT, AOUT, SOUT Pulse-Skipping Mode

During load steps, initial soft-start, end of soft-stop or light load operation (if the forward converter is designed to operate in DCM), the loop may require pulse skipping on the OUT pin. This occurs when the COMP pin falls below its switching threshold. If the COMP pin falls below it’s switching threshold while OUT is turned on, the LT3753 will immediately turn OUT off; both AOUT and SOUT will complete their normal signal timings referenced from the OUT falling edge. If the COMP pin remains below it’s switching threshold at the start of the next switching cycle, the LT3753 will skip the next OUT pulse and therefore also skip AOUT and SOUT pulses. For AOUT control, this prevents the active clamp switch from being accidentally discharged during missing OUT pulses and/or causing reverse saturation of the transformer. For SOUT control, this prevents the secondary side synchronous rectifier controller from incorrectly switching between forward FET and synchronous FET conduction. The LT3753 correctly re-establishes the required AOUT, SOUT control signals if the OUT signal is required for the next cycle.

AOUT Timeout

During converter start-up in soft-start, the switching frequency and maximum duty cycle clamp D_{VSEC} are both folded back. While this correctly reduces the effective minimum on time of the OUT pin (to allow control of inductor current for very low output voltages during start-up), this means the AOUT pin on time duration can be large. In order to ensure the active clamp switch controlled by AOUT does not stay on too long, the LT3753 has an internal 15\mu s timeout to turn off the AOUT signal. This prevents the active clamp capacitor from being connected across the transformer primary winding long enough to create reverse saturation.

Main Transformer Selection

The selection of the main transformer will depend on the applications requirements: isolation voltage, power level, maximum volt-seconds, turns ratio, component size, power losses and switching frequency.

Transformer construction using the planar winding technology is typically chosen for minimizing leakage inductance and reducing component height. Transformer core type is usually a ferrite material for high frequency applications.

Find a family of transformers that meet both the isolation and power level requirements of the application. The next step is to find a transformer within that family which is suitable for the application. The subsequent thought process for the transformer design will include:

(1) Secondary turns (N_S), core losses, temperature rise, flux density, switching frequency
(2) Primary turns (N_P), maximum duty cycle and reset voltages
(3) Copper losses

The expression for secondary turns (N_S) is given by,
N_S = 10^8 \frac{V_{OUT}}{f_{OSC} \cdot A_C \cdot B_M}
where,

\[ A_C = \text{cross-sectional area of the core in cm}^2 \]
\[ B_M = \text{maximum AC flux density desired} \]

For flux density, choose a level which achieves an acceptable level of core loss/temperature rise at a given switching frequency. The transformer data sheet will provide curves of core loss versus flux density at various switching frequencies. The data sheet will also provide temperature rise versus core loss. While choosing a value for BM to avoid excessive core losses will usually allow enough headroom for flux swing during input / load transients, still make sure to stay well below the saturation flux density of the transformer core. If needed, increasing \( N_S \) will reduce flux density. After calculating \( N_S \), the number of primary turns \( (N_P) \) can be calculated from,

\[ N_P = N_S \cdot D_{\text{MAX}} \frac{V_{\text{IN(MIN)}}}{V_{\text{OUT}}} \]

where,

\[ V_{\text{IN(MIN)}} = \text{minimum system input voltage} \]
\[ D_{\text{MAX}} = \text{maximum switch duty cycle at } V_{\text{IN(MIN)}} \text{ (typically chosen between 0.6 and 0.7)} \]

At minimum input voltage the converter will run at a maximum duty cycle \( D_{\text{MAX}} \). A higher transformer turns ratio \( (N_P/N_S) \) will create a higher \( D_{\text{MAX}} \) but it will also require higher voltages at the drain of the primary side switch to reset the transformer (see previous sections Lo side Active Clamp Topology and Hi side Active Clamp Topology). \( D_{\text{MAX}} \) values are typically chosen between 0.6 and 0.7. Even for a given \( D_{\text{MAX}} \) value, the loop must also provide protection against duty cycles that may excessively exceed \( D_{\text{MAX}} \) during transients or faults. While most converters only provide a fixed duty cycle clamp, the LT3753 provides a programmable maximum duty cycle clamp \( D_{VSEC} \) that also moves inversely with input voltage.

The resulting function is that of a programmable voltage-second clamp. This allows the user to choose a transformer turns ratio for \( D_{\text{MAX}} \) and then customize a maximum duty cycle clamp \( D_{VSEC} \) above \( D_{\text{MAX}} \) for safety. \( D_{VSEC} \) then follows the natural duty cycle of the converter as a safety guardrail (see previous section Programming Duty Cycle Clamp).

After deciding on the particular transformer and turns ratio, the copper losses can then be approximated by,

\[ P_{\text{CU}} = D \cdot I(\text{Load})_{(MAX)}^2 \left( R_{\text{SEC}} + \left( \frac{N_S}{N_P} \right)^2 R_{\text{PRI}} \right) \]

where,

\[ D = \text{switch duty cycle (choose nominal 0.5)} \]
\[ I(\text{Load})_{(MAX)} = \text{maximum load current} \]
\[ R_{\text{PRI}} = \text{primary winding resistance} \]
\[ R_{\text{SEC}} = \text{secondary winding resistance} \]

If there is a large difference between the core losses and the copper losses then the number of secondary turns can be adjusted to achieve a more suitable balance. The number of primary Turns should then be recalculated to maintain the desired turns ratio.

### Generating Auxiliary Supplies

In many isolated forward converter applications, an auxiliary bias may be required for the primary-side circuitry and/or the secondary-side circuitry. This bias is required for various reasons: to limit voltages seen by an IC, to improve efficiency, to remove power dissipation from inside an IC and/or to power an IC before target output voltage regulation is achieved (eg) during \( V_{\text{OUT}} \) start-up).

The best method for generating an auxiliary supply, that is available even for \( V_{\text{OUT}} = 0V \), is to have a housekeeping controller integrated into the primary-side IC (Figure 16). This gives the highest efficiency, most cost effective

---

**Figure 16. LT3752 Forward Controller with Additional Integrated Housekeeping Controller for Primary-Side and Secondary-Side Bias**
solution without the need for custom magnetics (limiting selection) or the need for an additional flyback controller IC. The LT3752 is a primary-side forward controller IC with an integrated housekeeping controller and can be easily substituted for the LT3753.

For isolated solutions without a housekeeping controller, there are alternative methods for generating an auxiliary supply for primary-side and secondary-side circuitry. Each method, however, will have trade-offs from the recommended housekeeping controller solution.

**Primary-Side Auxiliary Supply**

The LT3753 can operate without a primary-side auxiliary supply since the \( V_{IN} \) pin has a wide operational range. The current required for all of the gate drivers (OUT, AOUT and SOUT) is supplied by an internal linear regulator connected between \( V_{IN} \) and INTVCC. If the efficiency loss and/or power dissipation and/or current drive capability of that internal linear regulator is a limiting factor in the forward converter design, then a primary-side bias (\( V_{AUX1} \)) can be generated to overdrive the INTVCC pin (Figure 17). \( V_{AUX1} \) is generated using an extra winding (\( N_{AUX} \)) from the main power transformer in combination with an inductor (L1) and two Schottky diodes (D1, D2) to generate a buck-derived supply. A 1mH inductor will usually suffice and should be chosen to handle the maximum supply current required by INTVCC. See also the section INTVCC Regulator Bypassing and Operation in the Applications Information Section.

**Secondary-Side Auxiliary Supply**

There are various methods for generating an auxiliary supply to power secondary-side circuitry. The LT8311 synchronous rectifier controller and opto coupler driver IC can be powered in several ways including connection directly to \( V_{OUT} \). While this is the easiest method, there are various guidelines described in the LT8311 data sheet for

Figure 17. Primary-Side Bias \( V_{AUX1} \) (\( N_{AUX} \), L1, D1, D2)
powering it’s VIN pin. In most cases an auxiliary supply is the best approach. The following methods can be used to generate a bias (VAUX2) to power secondary-side circuitry:

1. Use a primary-side forward controller with integrated housekeeping controller to generate a secondary-side bias (Figure 16).

2. Use a buck-derived bias using an extra winding from the main power transformer (similar method as Figure 17, applied to secondary-side circuitry)

3. Use a custom output inductor with overwinding (Figure 18).

4. Use a peak-charge circuit (Figures 19 (a), (b), (c)).

Whichever method is used to create the auxiliary supply for secondary-side circuitry, the forward converter should be tested to ensure the auxiliary supply is acceptable for voltage range, supply current requirements and behavior during converter power-up/down.

**Primary-Side Power MOSFET Selection**

The selection of the primary-side N-channel power MOSFET M1 is determined by the maximum levels expected for the drain voltage and drain current. In addition, the power losses due to conduction losses, gate driver losses and transition losses will lead to a fine tuning of the MOSFET selection. If power losses are high enough to cause an unacceptable temperature rise in the MOSFET then several MOSFETs may be required to be connected in parallel.

The maximum drain voltage expected for the MOSFET M1 follows from the equations previously stated in the active clamp topology sections:

\[ V_{DS} (M1) = \frac{V_{IN}^2}{V_{IN} - (V_{OUT} \cdot N)} \]

The MOSFET should be selected with a BV\(_{DSS}\) rating approximately 20% greater than the above steady state \( V_{DS} \) calculation due to tolerances in duty cycle, load transients, voltage ripple on \( C_{CL} \) and leakage inductance spikes. A MOSFET with the lowest possible voltage rating for the application should be selected to minimize switch on resistance for improved efficiency. In addition, the MOSFET should be selected with the lowest gate charge to further minimize losses.
MOSFET M1 losses at maximum output current can be approximated as:

\[ P_{M1} = P_{\text{CONDUCTION}} + P_{\text{GATEDRIVER}} + P_{\text{TRANSITION}} \]

(i) \( P_{\text{CONDUCTION}} = \left( \frac{N_P}{N_S} \right) \cdot \left( \frac{V_{\text{OUT}}}{V_{\text{IN}}} \right) \cdot \left( \frac{N_S}{N_P} \cdot I_{\text{OUT(MAX)}} \right)^2 \cdot R_{\text{DS(ON)}} \)

Note: The on resistance of the MOSFET, \( R_{\text{DS(ON)}} \), increases with the MOSFET’s junction temperature. \( R_{\text{DS(ON)}} \) should therefore be recalculated once junction temperature is known. A final value for \( R_{\text{DS(ON)}} \) and therefore \( P_{\text{CONDUCTION}} \) can be achieved from a few iterations.

(ii) \( P_{\text{GATEDRIVER}} = (Q_{G} \cdot \text{INTVCC} \cdot f_{\text{OSC}}) \)

where,

\( Q_{G} = \) gate charge \( (V_{GS} = \text{INTVCC}) \)

(iii) \( P_{\text{TRANSITION}} = P_{\text{TURN_OFF}} + P_{\text{TURN_ON}} (\approx 0 \text{ if ZVS}) \)

(a) \( P_{\text{TURN_OFF}} = \frac{1}{2} I_{\text{OUT(MAX)}} \left( \frac{N_S}{N_P} \right) \left( \frac{V_{\text{IN}}}{1-D} \right) \left( \frac{Q_{GD}}{I_{\text{GATE}}} \right) \cdot f_{\text{OSC}} \)

where,

\( Q_{GD} = \) gate to drain charge

\( I_{\text{GATE}} = \) 2A source/sink for OUT pin gate driver

(b) \( P_{\text{TURN_ON}} = \frac{1}{2} I_{\text{OUT(MAX)}} \left( \frac{N_S}{N_P} \right) (V_{DS}) \left( \frac{Q_{GD}}{I_{\text{GATE}}} \right) \cdot f_{\text{OSC}} \)

where,

\( V_{DS} = \) M1 drain voltage at the beginning of M1 turn on

\( V_{DS} \) typically sits between \( V_{\text{IN}} \) and 0V (ZVS)

During programmable timing \( t_{\text{AO}} \), negative \( I_{\text{MAG}} \) discharges M1 drain SWP towards \( V_{\text{IN}} \) (Figure 1). ZVS is achieved if enough leakage inductance exists—to delay the secondary side from clamping M1 drain to \( V_{\text{IN}} \)—and if enough energy is stored in \( L_{MAG} \) to discharge SWP to 0V during that delay. (see Programming Active Clamp Switch Timing: \( A_{\text{OUT}} \) to OUT (\( t_{\text{AO}} \)).

Synchronous Control (SOUT)

The LT3753 uses the SOUT pin to communicate synchronous control information to the secondary side synchronous rectifier controller (Figure 20). The isolating transformer (\( T_{\text{SYNC}} \)), coupling capacitor (\( C_{\text{SYNC}} \)) and resistive load (\( R_{\text{SYNC}} \)) allow the ground referenced SOUT signal to generate positive and negative signals required at the SYNC input of the secondary side synchronous rectifier controller. For the typical LT3753 applications operating with an LT8311, \( C_{\text{SYNC}} \) is 220pF, \( R_{\text{SYNC}} \) is 560Ω and \( T_{\text{SYNC}} \) is typically a PULSE PE-68386NL.

Typically choose \( C_{\text{SYNC}} \) between 220pF and 1nF. \( R_{\text{SYNC}} \) should then be chosen to obey:

(1) \( \frac{\text{SOUT}_{\text{MAX}}}{100\text{mA}} \leq R_{\text{SYNC}} \leq \sqrt{\frac{L_{\text{MAG}}}{C_{\text{SYNC}}}} \)

where,

\( \text{SOUT}_{\text{MAX}} = \text{INTVCC} \)

\( L_{\text{MAG}} = T_{\text{SYNC}}'s \) magnetizing inductance

100mA = SOUT gate driver minimum source current and

(2) \( R_{\text{SYNC}} \cdot C_{\text{SYNC}} \geq (-1) \cdot \frac{Y}{\ln (Z/\text{SOUT}_{\text{MAX}})} \)

Figure 20. SOUT Pulse Transformer
where,

\[ Y = \text{SYNC minimum pulse duration (50ns; LT8311)} \]
\[ Z = |\text{SYNC level to achieve } Y| (\pm2V; \text{LT8311}) \]

Even though the LT3753 INTVCC pin is allowed to be over driven by as much as 15.4V, SOUT\text{MAX} level should be designed to not cause TSYNC output to exceed the maximum ratings of the LT8311’s SYNC pin.

**Cost/Space reduction**: If discontinuous conduction mode (DCM) operation is acceptable at light load, the LT8311 has a preactive mode which controls the synchronous MOSFETs without \( T_{\text{SYNC}} \), \( C_{\text{SYNC}} \), \( R_{\text{SYNC}} \) or the LT3753 timing resistors \( R_{\text{TAS}}, R_{\text{TO S}} \) (leave open).

**Output Inductor Value**

The choice of output inductor value \( L_{\text{OUT}} \) will depend on the amount of allowable ripple current. The inductor ripple current is given by:

\[
\Delta I_L = \frac{(V_{\text{OUT}}/(L_{\text{OUT}} \cdot f_{\text{OSC}})) \cdot (1 – (V_{\text{OUT}}/V_{\text{IN}})(N_{\text{P}}/N_{\text{S}}))}{8 \cdot f_{\text{OSC}}}
\]

The LT3753 allows very large \( \Delta I_L \) values (low \( L_{\text{OUT}} \) values) without the worry of insufficient slope compensation—by allowing slope compensation to be programmed with an external resistor in series with the ISENSEP pin (see Current Sensing and Programmable Slope Compensation).

Larger \( \Delta I_L \) will allow lower \( L_{\text{OUT}} \), reducing component size, but will also cause higher output voltage ripple and core losses. For LT3753 applications, \( \Delta I_L \) is typically chosen to be 40% of \( I_{\text{OUT(MAX)}} \).

**Output Capacitor Selection**

The choice of output capacitor value is dependent on output voltage ripple requirements given by:

\[
\Delta V_{\text{OUT}} \approx \Delta I_L(ESR + (1/(8 \cdot f_{\text{OSC}} \cdot C_{\text{OUT}}))
\]

where,

\[ \Delta I_L = \text{output inductor ripple current } I_{L(RIPPLE)(P-P)} \]
\[ ESR = \text{effective series resistance (of } C_{\text{OUT}}) \]
\[ f_{\text{OSC}} = \text{switching frequency} \]
\[ C_{\text{OUT}} = \text{output capacitance} \]

This gives:

\[
C_{\text{OUT}} = \frac{\Delta I_L}{8 \cdot f_{\text{OSC}} \cdot (\Delta V_{\text{OUT}} – \Delta I_L \cdot ESR)}
\]

Typically \( C_{\text{OUT}} \) is made up of a low ESR ceramic capacitor(s) to minimize \( \Delta V_{\text{OUT}} \). Additional bulk capacitance is added in the form of electrolytic capacitors to minimize output voltage excursions during load steps.

**Input Capacitor Selection**

The active clamp forward converter demands pulses of current from the input due to primary winding current and magnetizing current. The input capacitor is required to provide high frequency filtering to achieve an input voltage as close as possible to a pure DC source with low ripple voltage. For low impedance input sources and medium to low voltage input levels, a simple ceramic capacitor with low ESR should suffice. It should be rated to operate at a worst case RMS input current of:

\[
I_{\text{CIN(RMS)}} = (N_{\text{S}}/N_{\text{P}}) I_{\text{OUT(MAX)}}/2
\]

A small 1µF bypass capacitor should also be placed close to the IC between \( V_{\text{IN}} \) and GND.

As input voltage levels increase, any use of bulk capacitance to minimize input ripple can impact on solution size and cost. In addition, inputs with higher source impedance will cause an increase in voltage ripple. In these applications it is recommended to include an LC input filter. The output impedance of the input filter should remain below the negative input impedance of the DC/DC forward converter.
APPLICATIONS INFORMATION

PCB Layout/Thermal Guidelines

For proper operation, PCB layout must be given special attention. Critical programming signals must be able to coexist with high dv/dt signals. Compact layout can be achieved but not at the cost of poor thermal management. The following guidelines should be followed to approach optimal performance.

1. Ensure that a local bypass capacitor is used (and placed as close as possible) between VIN and GND for the controller IC(s).

2. The critical programming resistors for timing (pins TAO, TAS, TOS, TBLNK, IVSEC and RT) must use short traces to each pin. Each resistor should also use a short trace to connect to a single ground bus specifically connected to pin 18 of the IC (GND).

3. The current sense resistor for the forward converter must use short Kelvin connections to the ISENSEP and ISENSEN pins.

4. High dv/dt lines should be kept away from all timing resistors, current sense inputs, COMP pin, UVLO_VSEC/OVLO pins and the FB trace.

5. Gate driver traces (AOUT, SOUT, OUT) should be kept as short as possible.

6. When working with high power components, multiple parallel components are the best method for spreading out power dissipation and minimizing temperature rise. In particular, multiple copper layers connected by vias should be used to sink heat away from each power MOSFET.

7. Keep high switching current PGND paths away from signal ground. Also minimize trace lengths for those high current switching paths to minimize parasitic inductance.
Figure 21. 36V to 72V, 5V/20A 100W Active Clamp Isolated Forward Converter
PACKAGE DESCRIPTION

FE Package
Package Variation: FE38 (31)
38-Lead Plastic TSSOP (4.4mm)
(Reference LTC DWG # 05-08-1865 Rev B)
Exposed Pad Variation AB

RECOMMENDED SOLDER PAD LAYOUT

PIN NUMBERS 23, 25, 27, 29, 31, 33 AND 35 ARE REMOVED

NOTE:
1. CONTROLLING DIMENSION: MILLIMETERS
2. DIMENSIONS ARE IN MILLIMETERS
3. DRAWING NOT TO SCALE
4. RECOMMENDED MINIMUM PCB METAL SIZE FOR EXPOSED PAD ATTACHMENT
*DIMENSIONS DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.150mm (.006") PER SIDE

REVISION HISTORY

<table>
<thead>
<tr>
<th>REV</th>
<th>DATE</th>
<th>DESCRIPTION</th>
<th>PAGE NUMBER</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td>08/15</td>
<td>Changed SS1 and SS2 ABS MAX ratings</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Changed AOUT and SOUT driver times</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Clarified SS2 pin (Soft-Start: Comp Pin) conditions</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>3</td>
<td>3</td>
</tr>
<tr>
<td></td>
<td></td>
<td>5</td>
<td>5</td>
</tr>
<tr>
<td></td>
<td></td>
<td>6</td>
<td>6</td>
</tr>
<tr>
<td>B</td>
<td>08/19</td>
<td>Corrected Active Clamp Capacitor Equation</td>
<td>23</td>
</tr>
<tr>
<td>C</td>
<td>06/20</td>
<td>Corrected UVLO Typo</td>
<td>3</td>
</tr>
</tbody>
</table>

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**RELATED PARTS**

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>LT3752/LT3752-1</td>
<td>Active Clamp Synchronous Forward Controllers with Internal Housekeeping Controller</td>
</tr>
<tr>
<td>LT8311</td>
<td>Preactive Secondary Synchronous and Opto Control for Forward Converters</td>
</tr>
<tr>
<td>LTC3765/LTC3766</td>
<td>Synchronous No-Opto Forward Controller Chip Set with Active Clamp Reset</td>
</tr>
<tr>
<td>LTC3722/LTC3722-2</td>
<td>Synchronous Full Bridge Controllers</td>
</tr>
<tr>
<td>LT3748</td>
<td>100V Isolated Flyback Controller</td>
</tr>
<tr>
<td>LT3798</td>
<td>Off-Line Isolated No-Opto Flyback Controller with Active PFC</td>
</tr>
</tbody>
</table>

**TYPICAL APPLICATION**

**Figure 22. 18V to 72V, 12V/8A Active Clamp Isolated Forward Converter**

**Efficiency and Power Loss**

<table>
<thead>
<tr>
<th>LOAD CURRENT (A)</th>
<th>EFFICIENCY (%)</th>
<th>POWER LOSS (W)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>96</td>
<td>0</td>
</tr>
<tr>
<td>2</td>
<td>94</td>
<td>2</td>
</tr>
<tr>
<td>4</td>
<td>92</td>
<td>4</td>
</tr>
<tr>
<td>6</td>
<td>88</td>
<td>6</td>
</tr>
<tr>
<td>8</td>
<td>88</td>
<td>8</td>
</tr>
<tr>
<td>10</td>
<td>86</td>
<td>10</td>
</tr>
</tbody>
</table>

VIN = 48V